# ACPM-7392 UTMS1700/2100(1710-1755MHz) and UMTS1700(1750-1785MHz)

# **Data Sheet**



#### Description

The ACPM-7392 is a fully matched 10-pin surface mount module developed for UMTS Band4 and Band9. This power amplifier module operates in the 1710-1785MHz bandwidth. The ACPM-7392 meets stringent UMTS linearity requirements up to 28.4dBm output power in band4 and 28.0dBm output power in band9. The 4mmx4mm form factor package is self contained, incorporating 50ohm input and output matching networks

The ACPM-7392 features 5th generation of CoolPAM circuit technology which supports 3 power modes – bypass, mid and high power modes. The CoolPAM is stage bypass technology enhancing PAE (power added efficiency) at low and medium power range. Active bypass feature is added to 5th generation to enhance PAE further at low output range. This helps to extend talk time.

The power amplifier is manufactured on an advanced InGaP HBT (hetero-junction Bipolar Transistor) MMIC (microwave monolithic integrated circuit) technology offering state-of-the-art reliability, temperature stability and ruggedness.

#### Features

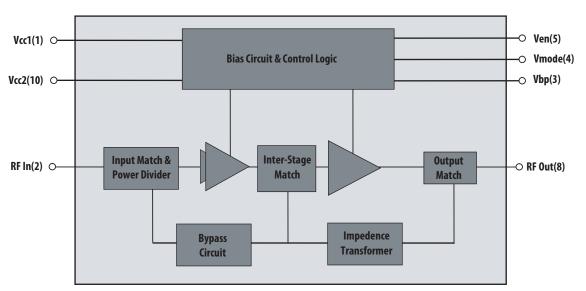
- Thin Package (0.9mm typ)
- Excellent Linearity
- 3-mode power control with Vbp and Vmode Bypass / Mid Power Mode / High Power Mode
- High Efficiency at max output power
- 10-pin surface mounting package
- Internal 500hm matching networks for both RF input and output
- Lead-free, RoHS compliant, Green

#### **Applications**

• UMTS Band4 and Band9

#### **Ordering Information**

Part Number	Number of Devices	Container
ACPM-7392-TR1	1,000	178mm (7") Tape/Reel
ACPM-7392-BLK	100	BULK



#### **Block Diagram**

## **Absolute Maximum Ratings**

No damage assuming only one parameter is set at limit at a time with all other parameters set at or below nominal value. Operation of any single parameter outside these conditions with the remaining parameters set at or below nominal values may result in permanent damage

Description	Min.	Тур.	Max.	Unit	
RF Input Power (Pin)		0	10 *	dBm	
DC Supply Voltage (Vcc1, Vcc2)	0	3.4	5.0	V	
Enable Voltage (Ven)	0	2.6	3.3	V	
Mode Control Voltage (Vmode)	0	2.6	3.3	V	
Bypass Control (Vbp)	0	2.6	3.3	V	
Storage Temperature (Tstg)	-55	25	+125	°C	

\* High Power Mode (5dBm for Bypass and Mid Power Mode)

#### **Recommended Operating Condition**

Description	Min.	Тур.	Max.	Unit	
DC Supply Voltage (Vcc1, Vcc2)	3.2	3.4	4.2	V	
Enable Voltage (Ven)					
Low	0	0	0.5	V	
High	1.35	2.6	3.1	V	
Mode Control Voltage (Vmode)					
Low	0	0	0.5	V	
High	1.35	2.6	3.1	V	
Bypass Control Voltage (Vbp)					
Low	0	0	0.5	V	
High	1.35	2.6	3.1	V	
Operating Frequency (fo)	1710		1785	MHz	
Ambient Temperature (Ta)	-20	25	85	°C	
Ambient temperature (1a)	-20	25	85	C	

#### **Operating Logic Table**

Power Mode	Ven	Vmode	Vbp	Pout (Rel99)	Pout (HSDPA, HSUPA MPR=0dB)
High Power Mode	High	Low	Low	~ 28.4 dBm (Band4) ~ 28.0 dBm (Band9)	~ 27.4 dBm (Band4) ~ 27.0 dBm (Band9)
Mid Power Mode	High	High	Low	~ 17 dBm	~ 16 dBm
Bypass Mode	High	High	High	~ 8 dBm	~ 7 dBm
Shut Down Mode	Low	Low	Low	-	-

#### **Electrical Characteristics for WCDMA Mode**

- Conditions: Vcc=3.4V, Ven=2.6V, T=25°, Zin/Zout=50ohm
- Signal Configuration: 3GPP (DPCCH + 1DPDCH) Up-Link unless specified otherwise.

Characteristics		Condition	Min.	Тур.	Max.	Unit
Operating Frequer	ncy Range		1710	-	1755	MHz
Gain		High Power Mode, Pout=28.4dBm	24.5	28.5		dB
		Mid Power Mode, Pout=17dBm	16	22.5		dB
		Bypass Mode, Pout=8dBm	8	12.5	16	dB
GPS Band Gain relative to Tx Gain, HPM		Ggps@Pin=-15dBm – Gtx@Pout=28.4dBm		-6	-1	dB
Rx Band Gain relati	ive to Tx Gain	Grx@Pin=-15dBm – Gtx@Pout=28.4dBm		-10	-6	dB
ISM Band Gain rela	tive to Tx Gain	Gism@Pin=-15dBm - Gtx@Pout=28.4dBm		-17	-4	dB
Power Added Effici	iency	High Power Mode, Pout=28.4dBm	36.3	40.2		%
		Mid Power Mode, Pout=17dBm	14.7	19.5		%
		Bypass Mode, Pout=8dBm	8.8	13.5		%
Total Supply Current		High Power Mode, Pout=28.4dBm		505	560	mA
		Mid Power Mode, Pout=17dBm		75	100	mA
		Bypass Mode, Pout=8dBm		13	20	mA
Quiescent Current		High Power Mode	75	100	125	mA
		Mid Power Mode	15	25	40	mA
		Bypass Mode	1	3	5	mA
Enable Current		High Power Mode		10	25	μΑ
		Mid Power Mode		10	25	μΑ
		Bypass Mode		10	25	μA
Mode Control Curr	ent	Mid Power Mode		5	25	μΑ
		Bypass Mode		5	25	μΑ
Bypass Control Cur	rrent	Bypass		5	25	μΑ
Total Current in Po	wer-down mode	Ven=0V, Vmode=0V, Vbp=0V			5	μΑ
Adjacent Channel Leakage Ratio	5 MHz offset 10 MHz offset	High Power Mode, Pout=28.4dBm		-41 -51	-36 -46	dBc dBc
	5 MHz offset 10 MHz offset	High Power Mode, Pout=27.4dBm (HSDPA, HSUPA MPR=0dB)		-38.5 -51	-36 -46	dBc dBc
	5 MHz offset	Mid Power Mode, Pout=17dBm		-45	-36	dBc
	10 MHz offset			-57	-46	dBc
	5 MHz offset	Mid Power Mode, Pout=16dBm		-43	-36	dBc
	10 MHz offset	(HSDPA, HSUPA MPR=0dB)		-56	-46	dBc
	5 MHz offset 10 MHz offset	Bypass Mode, Pout=8dBm		-46 -54	-36 -46	dBc dBc
	5 MHz offset	Bypass Mode, Pout=7dBm		-43	-36	dBc
	10 MHz offset	(HSDPA, HSUPA MPR=0dB)		-53	-46	dBc

#### **Electrical Characteristics for WCDMA Mode**

Characteristics		Condition	Min.	Тур.	Max.	Unit
Harmonic	Second	High Power Mode, Pout=28.4dBm		-41	-35	dBc
Suppression	Third			-62	-40	dBc
Gain at Harmonic	S	Second and Third			0	dB
Input VSWR		High Power Mode		1.5:1	2.5:1	
Stability (Spurious	s Output)	Load VSWR 5:1, All phase			-60	dBc
Rx Band Noise Pov	wer (Vcc=4.2V)	High Power Mode, Pout=28.4dBm		-141	-139	dBm/Hz
GPS Band Noise (	/cc=4.2V)	High Power Mode, Pout=28.4dBm		-138	-134	dBm/Hz
ISM Band Noise (V	/cc=4.2V)	High Power Mode, Pout=28.4dBm		-146	-143	dBm/Hz
Phase Discontinuity		HPM <> MPM, Pout=17dBm		19	45	deg
		MPM <> BPM, Pout=8dBm		40	60	deg
Ruggedness		Pout<28.4dBm & Pin<=5dBm, All phase, High Power Mode			8:1	VSWR

1. HSDPA

3GPP TS 34.121-1

User Equipment (UE) conformance specification; Radio transmission and reception (FDD); Part 1: Conformance specification Annex C (normative): Measurement channels

C.10.1 UL reference measurement channel for HSDPA tests

Table C.10.1.4:  $\beta$  values for transmitter characteristics tests with HS-DPCCH

Sub-test 2 (CM=1.0dB, MPR=0.0dB)

#### 2. HSUPA

3GPP TS 34.121-1

User Equipment (UE) conformance specification; Radio transmission and reception (FDD); Part 1: Conformance specification Annex C (normative): Measurement channels

C.11.1 UL reference measurement channel for E-DCH tests

Table C.11.1.3:  $\beta$  values for transmitter characteristics tests with HS-DPCCH and E-DCH

Sub-test 1 (CM=1.0dB, MPR=0.0dB)

## Electrical Characteristics for WCDMA Mode (Band9)

- Conditions: Vcc=3.4V, Ven=2.6V, T=25°, Zin/Zout=50ohm

- Signal Configuration: 3GPP (DPCCH + 1DPDCH) Up-Link unless specified otherwise.

Characteristics		Condition	Min.	Тур.	Max.	Unit
Operating Frequer	ncy Range		1750	-	1785	MHz
Gain		High Power Mode, Pout=28.0dBm	24.5	28.5		dB
		Mid Power Mode, Pout=17dBm	16.5	20.5		dB
		Bypass Mode, Pout=8dBm	9	13.0		dB
Power Added Efficiency		High Power Mode, Pout=28.0dBm	33.1	39.4		%
		Mid Power Mode, Pout=17dBm	14.6	19.5		%
		Bypass Mode, Pout=8dBm	8.8	14.1		%
Total Supply Curre	nt	High Power Mode, Pout=28.0dBm		470	560	mA
		Mid Power Mode, Pout=17dBm		75	100	mA
		Bypass Mode, Pout=8dBm		12.5	20	mA
Quiescent Current		High Power Mode	75	100	125	mA
		Mid Power Mode	15	25	40	mA
		Bypass Mode	1	3	5	mA
Enable Current		High Power Mode		10	25	μA
		Mid Power Mode		10	25	μΑ
		Bypass Mode		10	25	μA
Mode Control Curi	rent	Mid Power Mode		5	25	μA
		Bypass Mode		5	25	μΑ
Bypass Control Cu	rrent	Bypass		5	25	μΑ
Total Current in Po	wer-down mode	Ven=0V, Vmode=0V, Vbp=0V			5	μΑ
Adjacent Channel Leakage Ratio	5 MHz offset 10 MHz offset	High Power Mode, Pout=28.0dBm		-42 -52	-36 -46	dBc dBc
	5 MHz offset 10 MHz offset	High Power Mode, Pout=27.0dBm (HSDPA, HSUPA MPR=0dB)		-39 -51	-36 -46	dBc dBc
	5 MHz offset 10 MHz offset	Mid Power Mode, Pout=17dBm		-43 -57	-36 -46	dBc dBc
	5 MHz offset 10 MHz offset	Mid Power Mode, Pout=16dBm (HSDPA, HSUPA MPR=0dB)		-41 -57	-36 -46	dBc dBc
	5 MHz offset 10 MHz offset	Bypass Mode, Pout=8dBm		-44 -54	-36 -46	dBc dBc
	5 MHz offset 10 MHz offset	Bypass Mode, Pout=7dBm (HSDPA, HSUPA MPR=0dB)		-43 -53	-36 -46	dBc dBc
Harmonic Suppression	Second Third	High Power Mode, Pout=28.0dBm		-41 -62	-35 -40	dBc dBc

#### **Electrical Characteristics for WCDMA Mode (Band9)**

Characteristics	Condition	Min.	Тур.	Max.	Unit
Input VSWR	High Power Mode		1.5:1	2.5:1	
Stability (Spurious Output)	Load VSWR 5:1, All phase			-60	dBc
Rx Band Noise Power (Vcc=4.2V)	High Power Mode, Pout=28.0dBm		-133.5	-130	dBm/Hz
GPS Band Noise (Vcc=4.2V)	High Power Mode, Pout=28.0dBm		-137	-134	dBm/Hz
ISM Band Noise (Vcc=4.2V)	High Power Mode, Pout=28.0dBm		-146	-143	dBm/Hz
Phase Discontinuity	HPM <> MPM, Pout=17dBm		25	45	deg
	MPM <> BPM, Pout=8dBm		25	45	deg
Ruggedness	Pout<28.0dBm & Pin<=5dBm, All phase, High Power Mode			8:1	VSWR

1. HSDPA

3GPP TS 34.121-1

User Equipment (UE) conformance specification; Radio transmission and reception (FDD); Part 1: Conformance specification Annex C (normative): Measurement channels

C.10.1 UL reference measurement channel for HSDPA tests

Table C.10.1.4:  $\beta$  values for transmitter characteristics tests with HS-DPCCH

Sub-test 2 (CM=1.0dB, MPR=0.0dB)

#### 2. HSUPA

3GPP TS 34.121-1

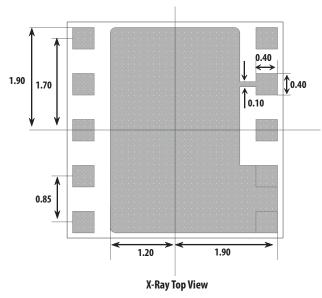
User Equipment (UE) conformance specification; Radio transmission and reception (FDD); Part 1: Conformance specification Annex C (normative): Measurement channels

C.11.1 UL reference measurement channel for E-DCH tests

Table C.11.1.3:  $\beta$  values for transmitter characteristics tests with HS-DPCCH and E-DCH

Sub-test 1 (CM=1.0dB, MPR=0.0dB)

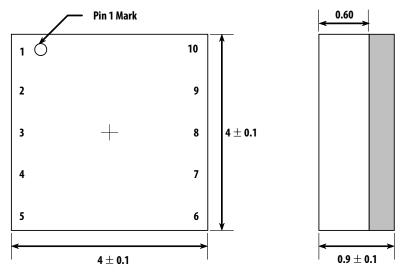
# Footprint



Pin #	Name	Description
1	Vcc1	DC Supply Voltage
2	RFin	RF Input
3	Vbp	Bypass Control
4	Vmode	Mode Control
5	Ven	PA Enable
6	GND	Ground
7	GND	Ground
8	RFout	RF Output
9	GND	Ground
10	Vcc2	DC Supply Voltage

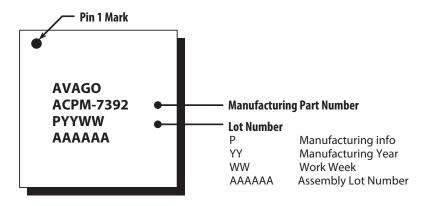
All dimensions are in millimeter

## **Package Dimensions**



All dimensions are in millimeter

# **Marking Specification**



#### CoolPAM

Avago Technologies' CoolPAM is stage-bypass PA technology which saves more power compared with conventional PA. With this technology, the ACPM-7392 has very low quiescent current, and efficiencies at low and medium output power ranges are high.

#### Incorporation of bias circuit

**PDF and Current** 

The ACPM-7392 has internal bias circuit, which removes the need for external constant voltage source (LDO). PA on/off is controlled by Ven. This is digitally control pin.

#### 3-mode power control with two mode control pins

The ACPM-7392 supports three power modes (bypass power mode/mid power mode/high power mode) with two mode control pins (Vmode and Vbp). This control scheme enables the ACPM-7392 to save power consumption more, which accordingly gives extended talk time.

PDF (probability density function) showing distribution of output power of mobile in real field gives motivation for stage-bypass PA. Output power is less than 16dBm for most of operating time (during talking), so it is important to save power consumption at low and medium output power ranges.

#### 5.00 700 4.50 CDG Urban 600 4.00 CDG Suburban 500 400 400 300 Current(mA) 3.50 3.00 2.50 2.00 1.50 200 1.00 100 0.50 0.00 0 -50 -40 -30 -20 -10 0 10 20 30 PA Out (dBm) Conventional PA Digitally control PA CoolPAM

#### Average current & Talk time

Average current consumed by PA can be calculated by summing up current at each output power weighted with probability. So it is expressed with integration of multiplication of current and probability at each output power.

Average current = 
$$\int (PDF \times Current) dp$$

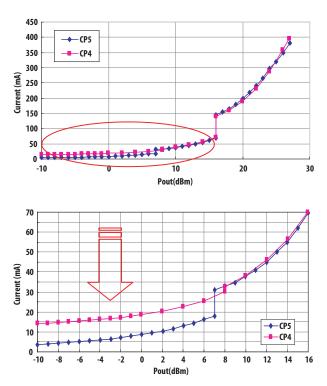
Talk time is extended more as average current consumption is lowered.

#### **Mode control pins**

Vmode and Vbp are digitally controlled by baseband and they control the operating mode of the PA. The operating logic table is summarized on the page 2. These pins do not require constant voltage for interface.

#### **UMTS PA performance comparison**

- CoolPAM 4 and CoolPAM 5

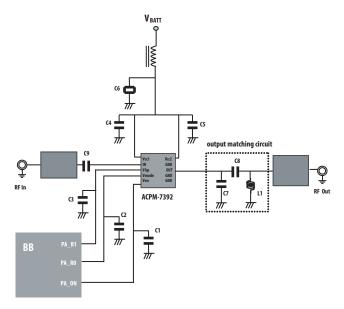


#### Icc Comparison of CP5 to CP4 (Avago CoolPAM)

The 5th generation of CoolPAM technology, ACPM-7392 can dramatically reduce Icc down to 3mA at bypass mode, which improves overall talk time and battery usage time of handset more compared with the CP4.

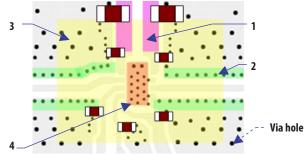
#### Application on mobile phone board

Application example in mobile is shown below. C4 and C5 should be placed close to pin1 and pin10. Bypass cap C1, C2 and C3 should be also placed nearby from pin5, pin4 and pin3, respectively. The length of post-PA transmission line should be minimized to reduce line loss.



**Peripheral Circuits** 

#### PCB layout and part placement on phone board

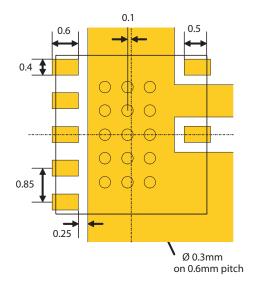


#### PCB guideline on phone board

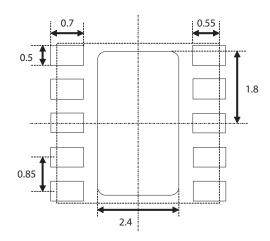
Notes

- 1. To prevent voltage drop, make the bias lines as wide as possible (Pink line).
- 2. Use many via holes to fence off PA RF input and output traces for better isolation. Output signal of the PA should be isolated from input signal and the receive signal. Output signal should not be fed into PA input. (Green line)
- 3. Use via holes to connect outer ground plates to internal ground planes. They help heat spread out more easily and accordingly the board temperature can be lowered. They also help to improve RF stability (Yellow square).
- 4. PA which has a ground slug requires many via holes which go through all the layers (Red square).

#### Metallization



#### **Solder Mask Opening**



#### **PCB Design Guidelines**

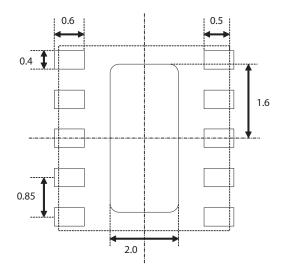
The recommended PCB land pattern is shown in figures on the left side. The substrate is coated with solder mask between the I/O and conductive paddle to protect the gold pads from short circuit that is caused by solder bleeding/bridging.

#### **Stencil Design Guidelines**

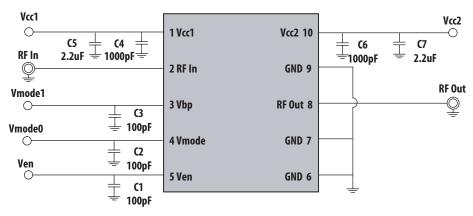
A properly designed solder screen or stencil is required to ensure optimum amount of solder paste is deposited onto the PCB pads.

The recommended stencil layout is shown here. Reducing the stencil opening can potentially generate more voids. On the other hand, stencil openings larger than 100% will lead to excessive solder paste smear or bridging across the I/O pads or conductive paddle to adjacent I/O pads. Considering the fact that solder paste thickness will directly affect the quality of the solder joint, a good choice is to use laser cut stencil composed of 0.100mm(4mils) or 0.127mm(5mils) thick stainless steel which is capable of producing the required fine stencil outline.

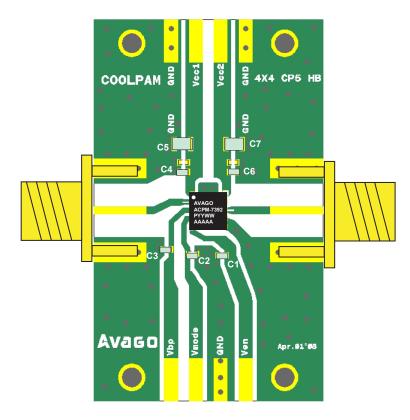
#### Solder Paste Stencil Aperture



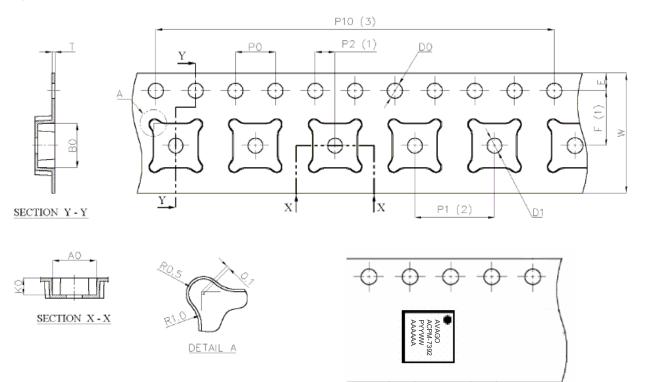
#### **Evaluation Board Schematic**



# **Evaluation Board Description**



# **Tape and Reel Information**

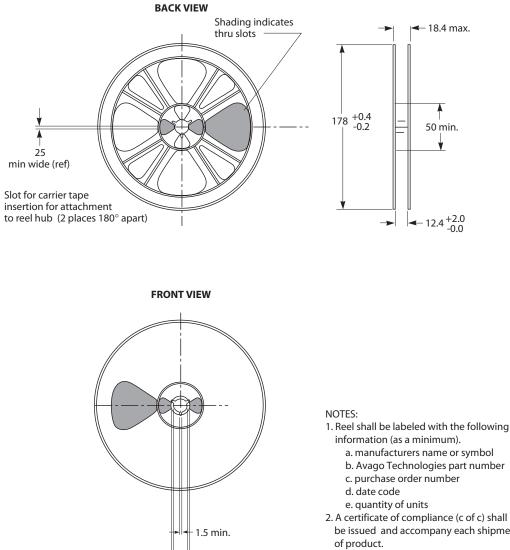


#### **Dimension List**

Annote	Millimeter	Annote	Millimeter
A0	4.40±0.10	P2	2.00±0.05
B0	4.40±0.10	P10	40.00±0.20
K0	1.70±0.10	E	1.75±0.10
D0	1.55±0.05	F	5.50±0.05
D1	1.60±0.10	W	12.00±0.30
P0	4.00±0.10	T	0.30±0.05
P1	8.00±0.10		

Tape and Reel Format – 4 mm x 4 mm.

## **Reel Drawing**



 $13.0\pm0.2$ 

 $21.0\pm0.8$ 

Plastic Reel Format (all dimensions are in millimeters)

- be issued and accompany each shipment
- 3. Reel must not be made with or contain ozone depleting materials.
- 4. All dimensions in millimeters (mm)

#### **Handling and Storage**

#### ESD (Electrostatic Discharge)

Electrostatic discharge occurs naturally in the environment. With the increase in voltage potential, the outlet of neutralization or discharge will be sought. If the acquired discharge route is through a semiconductor device, destructive damage will result.

ESD countermeasure methods should be developed and used to control potential ESD damage during handling in a factory environment at each manufacturing site.

#### **MSL (Moisture Sensitivity Level)**

Plastic encapsulated surface mount package is sensitive to damage induced by absorbed moisture and temperature.

Avago Technologies follows JEDEC Standard J-STD 020B. Each component and package type is classified for moisture sensitivity by soaking a known dry package at various temperatures and relative humidity, and times. After soak, the components are subjected to three consecutive simulated reflows.

The out of bag exposure time maximum limits are determined by the classification test describe below which corresponds to a MSL classification level 6 to 1 according to the JEDEC standard IPC/JEDEC J-STD-020B and J-STD-033.

ACPM-7392 is MSL3. Thus, according to the J-STD-033 p.11 the maximum Manufacturers Exposure Time (MET) for this part is 168 hours. After this time period, the part would need to be removed from the reel, de-taped and then re-baked. MSL classification reflow temperature for the ACPM-7392 is targeted at  $260^{\circ} + 0/-5^{\circ}$ . Figure and table on next page show typical SMT profile for maximum temperature of  $260 + 0/-5^{\circ}$ .

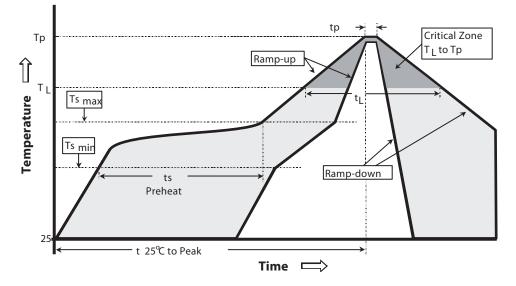
MSL Level	Floor Life (out of bag) at factory ambient $\leq$ 30°C/60% RH or as stated
1	Unlimited at $\leq$ 30°C/85% RH
2	1 year
2a	4 weeks
3	168 hours
4	72 hours
5	48 hours
5a	24 hours
6	Mandatory bake before use. After bake, must be reflowed within the time limit specified on the label

### **Moisture Classification Level and Floor Life**

Note :

1. The MSL Level is marked on the MSL Label on each shipping bag.

# **Reflow Profile Recommendations**



Typical SMT Reflow Profile for Maximum Temperature = 260 +0/ -5 $^\circ$
--

Profile Feature	Sn-Pb Solder	Pb-Free Solder		
Average ramp-up rate (TL to TP)	3°/sec max	3° /sec max		
Preheat				
- Temperature Min (Tsmin)	100°	150°		
- Temperature Max (Tsmax)	150°	200°		
- Time (min to max) (ts)	60-120 sec	60-180 sec		
Tsmax to TL				
- Ramp-up Rate		3° /sec max		
Time maintained above:				
- Temperature (TL)	183°	217°		
- Time (TL)	60-150 sec	60-150 sec		
Peak temperature (Tp)	240 +0/-5°	260 +0/-5°		
Time within 5° of actual Peak Temperature (tp)	10-30 sec	20-40 sec		
Ramp-down Rate	6° /sec max	6° /sec max		
Time 25° to Peak Temperature	6 min max.	8 min max.		

#### **Storage Condition**

Packages described in this document must be stored in sealed moisture barrier, antistatic bags. Shelf life in a sealed moisture barrier bag is 12 months at <40° and 90% relative humidity (RH) J-STD-033 p.7.

#### **Out-of-Bag Time Duration**

After unpacking the device must be soldered to the PCB within 168 hours as listed in the J-STD-020B p.11 with factory conditions  $<30^{\circ}$  and 60% RH.

#### Baking

It is not necessary to re-bake the part if both conditions (storage conditions and out-of bag conditions) have been satisfied. Baking must be done if at least one of the conditions above have not been satisfied. The baking conditions are 125° for 12 hours J-STD-033 p.8.

## CAUTION

Tape and reel materials typically cannot be baked at the temperature described above. If out-of-bag exposure time is exceeded, parts must be baked for a longer time at low temperatures, or the parts must be de-reeled, detaped, re-baked and then put back on tape and reel. (See moisture sensitive warning label on each shipping bag for information of baking).

#### **Board Rework**

#### **Component Removal, Rework and Remount**

If a component is to be removed from the board, it is recommended that localized heating be used and the maximum body temperatures of any surface mount component on the board not exceed 200°. This method will minimize moisture related component damage. If any component temperature exceeds 200°, the board must be baked dry per 4-2 prior to rework and/or component removal. Component temperatures shall be measured at the top center of the package body. Any SMD packages that have not exceeded their floor life can be exposed to a maximum body temperature as high as their specified maximum reflow temperature.

#### **Removal for Failure Analysis**

Not following the above requirements may cause moisture/reflow damage that could hinder or completely prevent the determination of the original failure mechanism.

#### **Baking of Populated Boards**

Some SMD packages and board materials are not able to withstand long duration bakes at 125°. Examples of this are some FR-4 materials, which cannot withstand a 24 hr bake at 125°. Batteries and electrolytic capacitors are also temperature sensitive. With component and board temperature restrictions in mind, choose a bake temperature from Table 4-1 in J-STD 033; then determine the appropriate bake duration based on the component to be removed. For additional considerations see IPC-7711 andIPC-7721.

#### **Derating due to Factory Environmental Conditions**

Factory floor life exposures for SMD packages removed from the dry bags will be a function of the ambient environmental conditions. A safe, yet conservative, handling approach is to expose the SMD packages only up to the maximum time limits for each moisture sensitivity level as shown in next table. This approach, however, does not work if the factory humidity or temperature is greater than the testing conditions of 30°/60% RH. A solution for addressing this problem is to derate the exposure times based on the knowledge of moisture diffusion in the component package materials ref. JESD22-A120). Recommended equivalent total floor life exposures can be estimated for a range of humidities and temperatures based on the nominal plastic thickness for each device.

Table on next page lists equivalent derated floor lives for humidities ranging from 20-90% RH for three temperature,  $20^{\circ}$ ,  $25^{\circ}$ , and  $30^{\circ}$ .

Table on next page is applicable to SMDs molded with novolac, biphenyl or multifunctional epoxy mold compounds. The following assumptions were used in calculating this table:

- 1. Activation Energy for diffusion = 0.35eV (smallest known value).
- For ≤60% RH, use Diffusivity = 0.121exp ( -0.35eV/kT) mm2/s (this used smallest known Diffusivity @ 30°).
- 3. For >60% RH, use Diffusivity = 1.320exp ( -0.35eV/kT) mm2/s (this used largest known Diffusivity @ 30°).

## Recommended Equivalent Total Floor Life (days) @ 20°, 25° & 30°, 35°

For ICs with Novolac, Biphenyl and Multifunctional Epoxies (Reflow at same temperature at which the component was classified) Maximum Percent Relative Humidity

Maximum Percent Relative Humidity

Package Type and Body Thickness	Moisture Sensitivity Level	5%	10%	<b>20</b> %	30%	<b>40</b> %	<b>50</b> %	60%	<b>70</b> %	<b>80</b> %	<b>90</b> %	
Body Thickness ≥3.1 mm	Level 2a	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	94	44	32	26	16	7	5	4	35°
ncluding	2010120	~	~	124	60	41	33	28	10	7	6	30°
PQFPs >84 pin, PLCCs (square) All MQFPs or		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~	167	78	53	42	36	14	10	8	25°
		$\infty$	$\infty$	231	103	69	57	47	19	13	10	20°
	Level 3	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~	8	7	6	6	6	4	3	3	35°
		$\infty$	$\infty$	10	9	8	7	7	5	4	4	30°
All BGAs ≥1 mm		~	~	13	11	10	9	9	7	6	5	25°
		$\infty$	$\infty$	17	14	13	12	12	10	8	7	20°
	Level 4	~	3	3	3	2	2	2	2	1	1	35°
		$\infty$	5	4	4	4	3	3	3	2	2	30°
		~	6	5	5	5	5	4	3	3	3	25°
		~	8	7	7	7	7	6	5	4	4	20°
	Level 5	$\infty$	2	2	2	2	1	1	1	1	1	35°
		$\infty$	4	3	3	2	2	2	2	1	1	30°
		$\infty$	5	5	4	4	3	3	2	2	2	25°
		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	7	7	6	5	5	4	3	3	3	20°
	Level 5a	$\infty$	1	1	1	1	1	1	1	1	1	35°
		$\infty$	2	1	1	1	1	1	1	1	1	30°
		~	3	2	2	2	2	2	1	1	1	25°
		~	5	4	3	3	3	2	2	2	2	20°
Body 2.1 mm ≤ Thickness <3.1 mm including PLCCs (rectangular)	Level 2a	$\infty$	$\infty$	$\infty$	$\infty$	58	30	22	3	2	1	35°
		~	~	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~	86	39	28	4	3	2	30°
		~	~	~	~	148	51	37	6	4	3	25°
		~	~	~	~	~	69	49	8	5	4	20°
8-32 pin	Level 3	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~	12	9	7	6	5	2	2	1	35°
OICs (wide body)		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~	19	12	9	8	7	3	2	2	30°
SOICs ≥20 pins, PQFPs ≤80 pins		~	~	25	15	12	10	9	5	3	3	25°
		∞	∞	32	19	15	13	12	7	5	4	20°
	Level 4	$\infty$	5	4	3	3	2	2	1	1	1	35°
		$\infty$	7	5	4	4	3	3	2	2	1	30°
		~	9	7	5	5	4	4	3	2	2	25°
		~	11	9	7	6	6	5	4	3	3	20°
	Level 5	~	3	2	2	2	2	1	1	1	1	35°
		~	4	3	3	2	2	2	1	1	1	30°
		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	5 6	4	3	3	3 4	3 4	2	1 3	1 2	25° 20°
	Laurin	~		5	5	4			3			
	Level 5a	~	1	1	1	1	1	1	1	0.5	0.5	35°
		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	2	1	1	1	1	1	1	0.5	0.5	30°
		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	2 3	2 2	2 2	2 2	2 2	2 2	1 2	1 2	1 1	25° 20°
		~										
Body Thickness <2.1 mm including SOICs <18 pin All TQFPs, TSOPs or All BGAs <1 mm body thickness	Level 2a	~	~	00	~	~	~	17	1 1	0.5 1	0.5 1	35° 30°
		~	~	~~~~	~	~	~	28	2	1	1	25°
		∞	∞	∞	∞	∞	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	∞	2	2	1	20°
	Level 3						8	5	1	0.5	0.5	35°
	Level 3	~	~	~~	~	~	8 11	5 7	1	0.5 1		30°
		∞	∞	∞	∞	∞	14	10	2	1	1 1	25°
		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~	~	20	13	2	2	1	20°
	Level 4	∞	00	00	7	4	3	2	1	0.5	0.5	35°
	Level 4	∞	~	~	9	5	4	2	1	1	1	30°
		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	12	7	5	4	2	1	1	25°
		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	17	9	7	6	2	2	1	20°
	Level 5	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	7	3	2	2	1	1	0.5	0.5	35°
	LeverJ	∞	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	13	5	2	2	2	1	0.5 1	0.5	30°
		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~	18	6	4	3	2	2	1	1	25°
		~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	~	26	8	6	5	4	2	2	1	20°
	Level 5a	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	7	20	1	1	1	1		0.5	0.5	 35°
	LEVEI Ja	∞	10	2	2	1	1	1	1	0.5 1	0.5	30°
		∞	13	5	2	2	2	2	1	1	0.5	50 25°
		~~	10	5	5	~	~	~				20

For product information and a complete list of distributors, please go to our web site: www.avagotech.com

Avago, Avago Technologies, and the A logo are trademarks of Avago Technologies in the United States and other countries. Data subject to change. Copyright © 2005-2009 Avago Technologies. All rights reserved. AV02-1907EN - May 8, 2009

